

830 series Silicon 25V hyperabrupt varactor diodes

ZC829, ZDC833, ZMV829, ZMDC830 and ZV831

Description

A range of silicon varactor diodes for use in frequency control and filtering. Featuring closely controlled CV characteristics and high Q. Low reverse current ensures very low phase noise performance. Available in single or dual common cathode format in a wide rage of miniature surface mount packages.

Features

- Close tolerance CV characteristics
- High tuning ratio
- Low I_R (typically 200pA)
- Excellent phase noise performance
- High Q
- · Range of miniature surface mount packages

Applications

- VCXO and TCXO
- Wireless communications
- Pagers
- Mobile radio



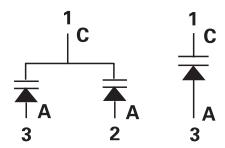
SOT23



SOD523

SOD323

SOT323



Where steeper CV slopes are required there is the 12V hyperabrupt range: **ZC930**, **ZMV930**, **ZV930** and **ZV931**

SOT23		SOD323	8	SOD523		SOT23		SOT323	:
Order code	Mark								
ZC829ATA	J9A	ZMV829ATA	AA						
ZC829BTA	J9B	ZMV829BTA	CA						
ZC830ATA	J1A	ZMV830ATA	AB						
ZC830BTA	J1B	ZMV830BTA	CB						
ZC831ATA	J3A	ZMV831ATA	AC						
ZC831BTA	J3B	ZMV831BTA	CC	ZV831BV2TA	81			ZMDC831BTA	CC
ZC832ATA	J4A	ZMV832ATA	AD						
ZC832BTA	J4B	ZMV832BTA	CD	ZV832BV2TA	82			ZMDC832BTA	CD
ZC833ATA	J2A	ZMV833ATA	AE			ZDC833ATA	C2A		
ZC833BTA	J2B	ZMV833BTA	CE						
ZC834ATA	J5A	ZMV834ATA	AF			ZDC834ATA	C5A		
ZC834BTA	J5B	ZMV834BTA	CF						
ZC835ATA	J6A	ZMV835ATA	AG						
ZC835BTA	J6B	ZMV835BTA	CG						
ZC836ATA	J7A								
ZC836BTA	J7B								

Order codes and device marking

Note:

The order codes are shown as TA which is for 7 inch reels. For 13 inch reels substitute TC in place of TA in the order code.

Tape and reel information

Reel code	Reel size (inches)	Tape width (millimeters)	Quantity per reel	
TA	7	8	3,000	
TC	13	8	10,000	

Part	Capacitance (pF) V _R =2V, f=1MHz			Min Q V _R = 3V f = 50MHz	C ₂ /	nce ratio ' C ₂₀ 1MHz
	Min.	Nom.	Max.		Min.	Max.
829A	7.38	8.2	9.02	250	4.3	5.8
829B	7.79	8.2	8.61	250	4.3	5.8
830A	9.0	10.0	11.0	300	4.5	6.0
830B	9.5	10.0	10.5	300	4.5	6.0
831A	13.5	15.0	16.5	300	4.5	6.0
831B	14.25	15.0	15.75	300	4.5	6.0
832A	19.8	22.0	24.2	200	5.0	6.5
832B	20.9	22.0	23.1	200	5.0	6.5
833A	29.7	33.0	36.3	200	5.0	6.5
833B	31.35	33.0	34.65	200	5.0	6.5
834A	42.3	47.0	51.7	200	5.0	6.5
834B	44.65	47.0	49.35	200	5.0	6.5
835A	61.2	68.0	74.8	100	5.0	6.5
835B	64.6	68.0	71.4	100	5.0	6.5
836A	90.0	100.0	110.0	100	5.0	6.5
836B	95.0	100.0	105.0	100	5.0	6.5

Tuning characteristics at $T_{amb} = 25^{\circ}C$

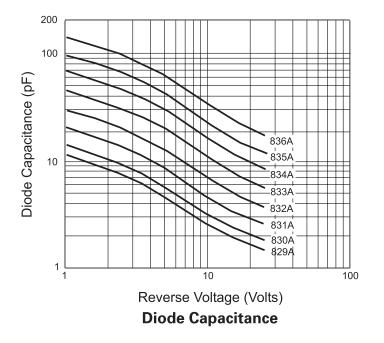
Absolute maximum ratings

Parameter	Symbol	Max.	Unit
Forward current	١ _F	200	mA
Power dissipation at T _{amb} = 25°C SOT23	P _{tot}	330	mW
Power dissipation at $T_{amb} = 25^{\circ}C \text{ SOD323}$	P _{tot}	330	mW
Power dissipation at $T_{amb} = 25^{\circ}C \text{ SOD523}$	P _{tot}	250	mW
Operating and storage temperature range		-55 to +150	°C

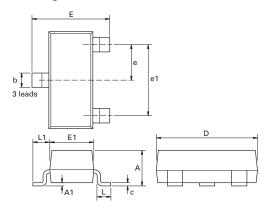
Electrical characteristics at $T_{amb} = 25^{\circ}C$

Paramater	Conditions	Min.	Тур.	Max.	Unit
Reverse breakdown voltage	I _R = 10μA	25			V
Reverse voltage leakage	V _R = 20V		0.2	20	nA
Temperature coefficient of capacitance	V _R = 3V, f = 1MHz		300	400	ppCm/°C

Typical characteristics



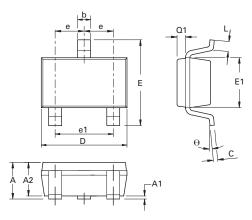
Package outline - SOT23



Dim.	Millin	Millimeters		Inches		Millim	eters	Inc	hes
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
A	2.67	3.05	0.105	0.120	Н	0.33	0.51	0.013	0.020
В	1.20	1.40	0.047	0.055	К	0.01	0.10	0.0004	0.004
С	-	1.10	-	0.043	L	2.10	2.50	0.083	0.0985
D	0.37	0.53	0.015	0.021	М	0.45	0.64	0.018	0.025
F	0.085	0.15	0.0034	0.0059	N	0.95 N	ЮМ	0.0375	5 NOM
G	1.90	NOM	0.075	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Package outline - SOT323

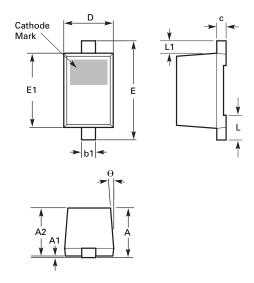


Dim.	Millimeters		Inches		Dim.	Millim	eters	Inc	hes
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
A	0.80	1.10	0.0315	0.0433	E1	1.15	1.35	0.0453	0.0532
A1	0	0.10	0	0.0039	е	0.65	BSC	0.025	6 BSC
A2	0.80	1.00	0.0315	0.394	e1	1.30	BSC	0.051	2 BSC
b	0.25	0.40	0.0098	0.0158	L	0.10	0.30	0.0039	0.0118
С	0.10	0.26	0.0039	0.0102	Q1	0.10	0.40	0.0039	0.0158
D	1.80	2.20	0.0709	0.0866	θ	0°	30°	0°	30°
E	1.80	2.40	0.0709	0.0945	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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Package outline - SOD523



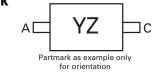
DIM	Millimeters Inches DIM Millimeters		neters	Inches					
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
А	-	0.800	-	0.0314	E	1.500	1.700	0.0590	0.0669
A1	0.000	0.100	0.000	0.0039	E1	1.100	1.300	0.0433	0.0511
A2	0.600	0.800	0.0236	0.0314	L	0.200	0.400	0.0078	0.0157
b1	0.160	0.300	0.0062	0.0118	L1	0.170	0.230	0.0066	0.0090
С	0.080	0.220	0.0031	0.0086	U	4°	10°	4°	10°
D	0.700	0.900	0.0275	0.0354	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

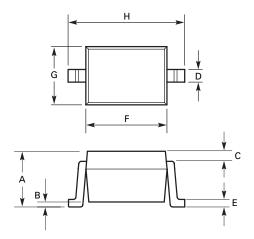
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Package outline - SOD323

Top mark



Top view



DIM	Millimeters		DIM	Millin	neters
	Min.	Max.		Min.	Max.
A	0.91	1.16	E	0.127	0.200
В	0.00	0.10	F	1.52	1.77
С	-	-	G	1.11	1.37
D	0.33	0.40	Н	2.46	2.71

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